

# DS26F31C/DS26F31M Quad High Speed Differential Line Driver

### **General Description**

The DS26F31 is a quad differential line driver designed for digital data transmission over balanced lines. The DS26F31 meets all the requirements of EIA Standard RS-422 and Federal Standard 1020. It is designed to provide unipolar differential drive to twisted-pair or parallel-wire transmission lines.

The DS26F31 offers improved performance due to the use of state-of-the-art L-FAST bipolar technology. The L-FAST technology allows for higher speeds and lower currents by utilizing extremely short gate delay times. Thus, the DS26F31 features lower power, extended temperature range, and improved specifications.

The circuit provides an enable and disable function common to all four drivers. The DS26F31C/DS26F31M features TRI-STATE® outputs and logical OR-ed complementary enable inputs. The inputs are all LS compatible and are all one unit load.

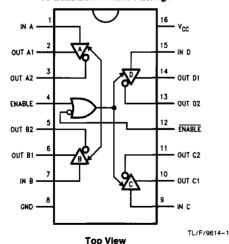
The DS26F31C/DS26F31M offers optimum performance when used with the DS26F32 Quad Differential Line Receiver.

#### **Features**

- Military temperature range
- Output skew—2.0 ns typical
- Input to output delay-10 ns
- Operation from single +5.0V supply
- 16-lead ceramic DIP Package
- Outputs won't load line when V<sub>CC</sub> = 0V
- Output short circuit protection
- Meets the requirements of EIA standard RS-422
- High output drive capability for 100Ω terminated transmission lines

### **Connection and Logic Diagrams**

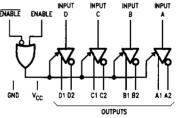
#### 16-Lead Dual-In-Line Package



Order Number DS26F31CJ or DS26F31MJ See NS Package Number J16A

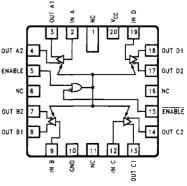
For Complete Military 883 Specifications, see RETS Data Sheet. Order Number DS26F31ME/883, DS26F31MJ/883, or DS26F31MW/883

See NS Package Numbers E20A, J16A, or W16A



TL/F/9614-2

FIGURE 1. Logic Symbol 20-Lead Ceramic Leadless Chip Carrier (E)



TL/F/9614-7

### Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature Range

-65°C to +175°C Ceramic DIP

Lead Temperature

Ceramic DIP (Soldering, 60 sec.)

Maximum Power Dissipation\* at 25°C

Cavity Package

Supply Voltage

Input Voltage Output Voltage

\*Derate cavity package 10 mW/°C above 25°C.

# **Operating Range**

DS26F31C

Temperature Supply Voltage

0°C to +70°C 4.75V to 5.25V

DS26F31M

Temperature Supply Voltage -55°C to +125°C 4.5V to 5.5V

#### Electrical Characteristics over operating range, unless otherwise specified (Notes 2 & 3)

300°C

7.0V

7.0V

5.5V

1500 mW

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V <sub>OH</sub>	Output Voltage HIGH	V <sub>CC</sub> = Min, I <sub>OH</sub> = -20 mA	2.5	3.2		V
VOL	Output Voltage LOW	V <sub>CC</sub> = Min, I <sub>OL</sub> = 20 mA		0.32	0.5	V
V <sub>iH</sub>	Input Voltage HIGH	V <sub>CC</sub> = Min	2.0			V
V <sub>IL</sub>	Input Voltage LOW	V <sub>CC</sub> = Max			0.8	V
I <sub>IL</sub>	Input Current LOW	V <sub>CC</sub> = Max, V <sub>I</sub> = 0.4V		-0.10	-0.20	mA
(iH	Input Current HIGH	V <sub>CC</sub> = Max, V <sub>I</sub> = 2.7V		0.5	20	μΑ
IIR	Input Reverse Current	V <sub>CC</sub> = Max, V <sub>I</sub> = 7.0V		0.001	0.1	mA
loz	Off State (High Impedance) Output Current	$V_{CC} = Max$ $V_{O} = 2.5V$		0.5	20	μΑ
		$V_{O} = 0.5V$		0.5	-20	
V <sub>IC</sub>	Input Clamp Voltage	$V_{CC} = Min, i_1 = -18 \text{ mA}$		-0.8	-1.5	V
los	Output Short Circuit	V <sub>CC</sub> = Max (Note 4)	-30	-60	- 150	mA
Iccx	Supply Current	V <sub>CC</sub> = Max, All Outputs Disabled			50	mA
lcc	1	V <sub>CC</sub> = Max, All Outputs Enabled			40	mA
t <sub>PLH</sub>	Input to Output	V <sub>CC</sub> = 5.0V, T <sub>A</sub> = 25°C, Load = Note 5, Note 6		10	15	ns
t <sub>PHL</sub>	Input to Output	V <sub>CC</sub> = 5.0V, T <sub>A</sub> = 25°C, Load = Note 5		10	15	ns
SKEW	Output to Output	V <sub>CC</sub> = 5.0V, T <sub>A</sub> = 25°C, Load = Note 5, Note 6		2.0	4.5	ns
t <sub>LZ</sub>	Enable to Output	$V_{CC} = 5.0V, T_A = 25^{\circ}C,$ $C_L = 10 \text{ pF}$		23	32	ns
t <sub>HZ</sub>	Enable to Output	V <sub>CC</sub> = 5.0V, T <sub>A</sub> = 25°C, C <sub>L</sub> = 10 pF		15	25	ns
t <sub>ZL</sub>	Enable to Output	V <sub>CC</sub> = 5.0V, T <sub>A</sub> = 25°C, Load = Note 5		20	30	ns
<sup>t</sup> zH	Enable to Output	V <sub>CC</sub> = 5.0V, T <sub>A</sub> = 25°C, Load = Note 5		23	32	ns

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" provide conditions for actual device operation.

Note 2: Unless otherwise specified min/max limits apply across the -55°C to +125°C temperature range for the DS26F31M and across the O°C to +70°C range for the DS26F31C. All typicals are given for V<sub>CC</sub> = 5V and T<sub>A</sub> = 25°C.

Note 3: All currents into the device pins are positive; all currents out of the device pins are negative. All voltages are referenced to ground unless otherwise specified

Note 4: Only one output at a time should be shorted.

Note 5: CL = 30 pF, VI = 1.3V to VO = 1.3V, VPULSE = 0V to +3V (See AC Load Test Circuit for TRI-STATE Outputs).

Note 6: Skew is defined as the difference in propagation delays between complementary outputs at the 50% point.

# **Test Circuit and Timing Waveforms**

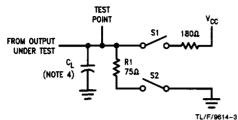


FIGURE 2. AC Load Test Circuit for TRI-STATE Outputs

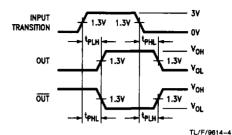
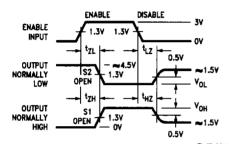


FIGURE 3. Propagation Delay (Notes 1 and 3)



 $_{\text{TL/F/9614-5}}$  FIGURE 4. Enable and Disable Times (Notes 2 and 3)

Note 1: Diagram shown for Enable Low. Switches S1 and S2 open.

Note 2: S1 and S2 of Load Circuit are closed except where shown.

Note 3: Pulse Generator for all Pulses: Rate  $\leq$  1.0 MHz,  $Z_{O}=50\Omega,\,t_{r}\leq6.0$  ns,  $t_{f}\leq6.0$  ns.

Note 4: CL includes probe and jig capacitance.

# **Typical Application**

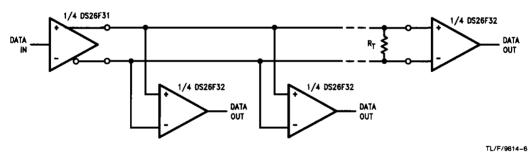


FIGURE 5. Typical Application

3-21